

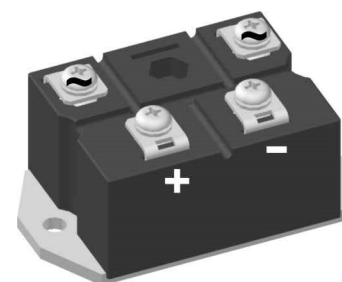
Standard Rectifier Module

1~ Rectifier	
V_{RRM}	= 800 V
I_{DAV}	= 60 A
I_{FSM}	= 550 A

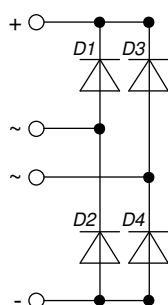
1~ Rectifier Bridge

Part number

VBO52-08NO7



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: PWS-D

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				900	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				800	V
I_R	reverse current	$V_R = 800\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$			40	μA
		$V_R = 800\text{ V}$	$T_{VJ} = 150^{\circ}\text{C}$			1.5	mA
V_F	forward voltage drop	$I_F = 20\text{ A}$	$T_{VJ} = 25^{\circ}\text{C}$			1.07	V
		$I_F = 40\text{ A}$				1.19	V
		$I_F = 20\text{ A}$	$T_{VJ} = 125^{\circ}\text{C}$			0.96	V
		$I_F = 40\text{ A}$				1.13	V
I_{DAV}	bridge output current	$T_C = 115^{\circ}\text{C}$ rectangular	$T_{VJ} = 150^{\circ}\text{C}$ d = 0.5			60	A
V_{F0}	threshold voltage	} for power loss calculation only		$T_{VJ} = 150^{\circ}\text{C}$		0.78	V
r_F	slope resistance					8.1	m Ω
R_{thJC}	thermal resistance junction to case					1.1	K/W
R_{thCH}	thermal resistance case to heatsink				0.4		K/W
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$				110	W
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}\text{C}$			550	A
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$			595	A
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^{\circ}\text{C}$			470	A
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$			505	A
I^2t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}\text{C}$			1.52	kA ² s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$			1.48	kA ² s
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^{\circ}\text{C}$			1.11	kA ² s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$			1.06	kA ² s
C_J	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$			19		pF

Package PWS-D				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal				150	A
T_{VJ}	virtual junction temperature			-40		150	°C
T_{op}	operation temperature			-40		125	°C
T_{stg}	storage temperature			-40		125	°C
Weight					153		g
M_D	mounting torque			4.25		5.75	Nm
M_T	terminal torque			4.25		5.75	Nm
$d_{Spp/Apb}$	creepage distance on surface striking distance through air	terminal to terminal		9.5			mm
$d_{Spp/Apb}$		terminal to backside		26.0			mm
V_{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000			V
		t = 1 minute		2500			V



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VBO52-08NO7	VBO52-08NO7	Box	10	472379

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}\text{C}$

		Rectifier	
$V_{0\max}$	threshold voltage	0.78	V
$R_{0\max}$	slope resistance *	6.9	mΩ

Technical drawing of a mechanical part, showing top and side views with dimensions.

Top View Dimensions:

- Overall width: 72
- Overall height: 42
- Top section width segments: 20, 18, 20
- Top section height segments: 2,5, 5,3, 13,3
- Bottom section width segments: 23, 10
- Bottom section height segments: 5,3, 13,3
- Central hexagonal feature: 18 (width), 10 (height)
- Left and right circular features: 21,6 (height), 5,3 (width)
- Bottom circular features: 2,5 (height), 3 (width)

Side View Dimensions:

- Overall height: 30
- Top section height segments: 2,5, 7
- Bottom section height segments: 3, 7

Other Features:

- Central hexagonal feature with a cross symbol (+) and a minus symbol (-).
- Left and right circular features with a tilde symbol (~).
- Bottom circular features with a plus symbol (+) and a minus symbol (-).
- Material specification: M5.



Rectifier


Fig. 1 Forward current vs. voltage drop per diode



Fig. 2 Surge overload current vs. time per diode

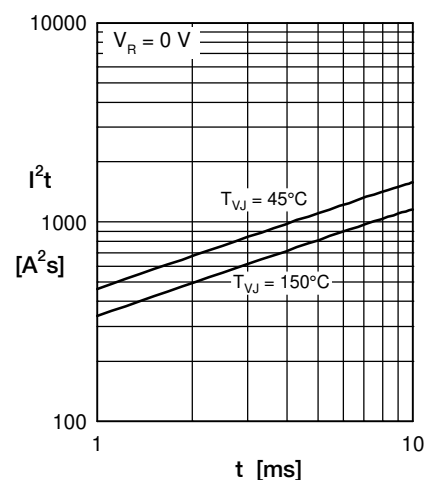


Fig. 3 I^2t vs. time per diode



Fig. 4 Power dissipation vs. forward current and ambient temperature per diode



Fig. 5 Max. forward current vs. case temperature per diode



Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.05	0.001
2	0.14	0.030
3	0.25	0.060
4	0.35	0.130
5	0.31	0.920